SEMICONDUCTOR

# 74LCX32500

# Low Voltage 36-Bit Universal Bus Transceivers with 5V Tolerant Inputs and Outputs

#### **General Description**

These 36-bit universal bus transceivers combine D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in <u>each</u> direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and CLKBA) inputs.

The LCX32500 is designed for low voltage (2.5V or 3.3V)  $V_{CC}$  applications with the capability of interfacing to a 5V signal environment.

The LCX32500 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power.

#### Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V<sub>CC</sub> specifications provided
- 6.0 ns t<sub>PD</sub> max (V<sub>CC</sub> = 3.3V), 20 µA I<sub>CC</sub> max
- Power down high impedance inputs and outputs

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- Supports live insertion/withdrawal (Note 1)
- $\blacksquare$  ±24 mA output drive (V<sub>CC</sub> = 3.0V)
- Uses patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
  - Human body model > 2000V Machine model > 200V
- Packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power up or down,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  and OE tied to GND through a resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

#### **Ordering Code:**

Order Number	Package Number	Package Description
74LCX32500G (Note 2)(Note 3)	BGA114A	114-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
Note 2. Ordering code	"O" indicates Trous	

Note 2: Ordering code "G" indicates Trays.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

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# 74LCX32500

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(	Top Thru View)

#### Truth Table (Note 4)

	Inpu	uts		Output
OEAB <sub>n</sub>	LEAB <sub>n</sub>	CLKAB <sub>n</sub>	An	Bn
L	Х	Х	Х	Z
Н	Н	Х	L	L
н	н	Х	н	н
н	L	$\downarrow$	L	L
н	L	$\downarrow$	н	н
н	L	н	Х	B <sub>0</sub> (Note 5)
н	L	L	Х	B <sub>0</sub> (Note 5) B <sub>0</sub> (Note 6)

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial (HIGH or LOW, inputs may not float)

Z = High Impedance

Note 4: A-to-B data flow is shown: B-to-A flow is similar but uses  $\overline{\text{OEBA}},$  LEBA, and  $\overline{\text{CLKBA}}.$ 

Note 5: Output level before the indicated steady-state input conditions were established.

Note 6: Output level before the indicated steady-state input conditions were established, provided that  $\overrightarrow{\text{CLKAB}}$  was LOW before LEAB went LOW.

#### **Functional Description**

For A-to-B data flow, the LCX32500 operates in the transparent mode when LEAB is HIGH. When LEAB is LOW, the A data is latched if CLKAB is held at a HIGH or LOW logic level. If LEAB is LOW, the A bus data is stored in the latch/flip-flop on the HIGH-to-LOW transition of CLKAB. Output-enable OEAB is active-HIGH. When OEAB is

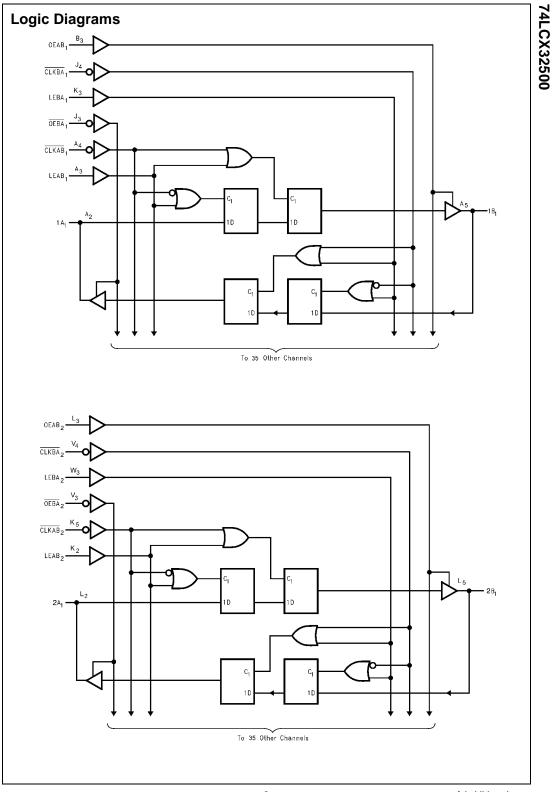
#### **Pin Descriptions**

Pin Names	Description
1A <sub>1</sub> - 1A <sub>18</sub>	Data Register A Inputs/3-STATE Outputs
2A <sub>1</sub> - 2A <sub>18</sub>	
1B <sub>1</sub> - 1B <sub>18</sub>	Data Register B Inputs/3-STATE Outputs
2B <sub>1</sub> - 2B <sub>18</sub>	
CLKAB <sub>1</sub> , CLKBA <sub>1</sub>	Clock Pulse Inputs
$\overline{\text{CLKAB}}_2, \overline{\text{CLKBA}}_2$	
LEAB <sub>1</sub> , LEBA <sub>1</sub>	Latch Enable Inputs
LEAB <sub>2</sub> , LEBA <sub>2</sub>	
OEAB <sub>1</sub> , OEBA <sub>1</sub>	Output Enable Inputs
$OEAB_2, \overline{OEBA}_2$	

#### **FBGA Pin Assignments**

	1	2	3	4	5	6
Α	1A <sub>2</sub>	1A <sub>1</sub>	LEAB <sub>1</sub>	CLKAB <sub>1</sub>	1B <sub>1</sub>	1B <sub>2</sub>
В	1A <sub>4</sub>	1A <sub>3</sub>	OEAB <sub>1</sub>	GND	1B <sub>3</sub>	1B <sub>4</sub>
С	1A <sub>6</sub>	1A <sub>5</sub>	GND	GND	1B <sub>5</sub>	1B <sub>6</sub>
D	1A <sub>8</sub>	1A <sub>7</sub>	V <sub>CC</sub>	V <sub>CC</sub>	1B <sub>7</sub>	1B <sub>8</sub>
E	1A <sub>10</sub>	1A <sub>9</sub>	GND	GND	1B <sub>9</sub>	1B <sub>10</sub>
F	1A <sub>12</sub>	1A <sub>11</sub>	GND	GND	1B <sub>11</sub>	1B <sub>12</sub>
G	1A <sub>14</sub>	1A <sub>13</sub>	V <sub>CC</sub>	V <sub>CC</sub>	1B <sub>13</sub>	1B <sub>14</sub>
н	1A <sub>15</sub>	1A <sub>16</sub>	GND	GND	1B <sub>16</sub>	1B <sub>15</sub>
J	1A <sub>17</sub>	1A <sub>18</sub>	OEBA <sub>1</sub>	CLKBA <sub>1</sub>	1B <sub>18</sub>	1B <sub>17</sub>
К	NC	$LEAB_2$	LEBA <sub>1</sub>	GND	CLKAB <sub>2</sub>	NC
L	2A <sub>2</sub>	2A <sub>1</sub>	$OEAB_2$	GND	2B <sub>1</sub>	2B <sub>2</sub>
м	2A <sub>4</sub>	2A <sub>3</sub>	GND	GND	2B <sub>3</sub>	2B <sub>4</sub>
N	2A <sub>6</sub>	2A <sub>5</sub>	V <sub>CC</sub>	V <sub>CC</sub>	2B <sub>5</sub>	2B <sub>6</sub>
Р	2A <sub>8</sub>	2A <sub>7</sub>	GND	GND	2B <sub>7</sub>	2B <sub>8</sub>
R	2A <sub>10</sub>	2A <sub>9</sub>	GND	GND	2B <sub>9</sub>	2B <sub>10</sub>
Т	2A <sub>12</sub>	2A <sub>11</sub>	V <sub>CC</sub>	V <sub>CC</sub>	2B <sub>11</sub>	2B <sub>12</sub>
U	2A <sub>14</sub>	2A <sub>13</sub>	GND	GND	2B <sub>13</sub>	2B <sub>14</sub>
v	2A <sub>15</sub>	2A <sub>16</sub>	$\overline{\text{OEBA}}_2$	CLKBA <sub>2</sub>	2B <sub>16</sub>	2B <sub>15</sub>
W	2A <sub>17</sub>	2A <sub>18</sub>	LEBA <sub>2</sub>	GND	2B <sub>18</sub>	2B <sub>17</sub>

HIGH, the outputs are active. When OEAB is LOW, the outputs are in the high impedance state.



74LCX32500

I<sub>GND</sub>

 $\mathsf{T}_{\mathsf{STG}}$ 

#### Absolute Maximum Ratings(Note 7)

Symbol	Parameter	Value	Conditions
V <sub>CC</sub>	Supply Voltage	-0.5 to +7.0	
VI	DC Input Voltage	-0.5 to +7.0	
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE
		$-0.5$ to $V_{CC} + 0.5$	Output in HIGH or LOW State (Note 8)
I <sub>IK</sub>	DC Input Diode Current	-50	V <sub>I</sub> < GND
I <sub>OK</sub>	DC Output Diode Current	-50	V <sub>O</sub> < GND
		+50	$V_{O} > V_{CC}$
I <sub>O</sub>	DC Output Source/Sink Current	±50	
lcc	DC Supply Current per Supply Pin	±100	

Units V V V

> mA mA mA

mΑ

°C

#### **Recommended Operating Conditions (Note 9)**

DC Ground Current per Ground Pin

Storage Temperature

Symbol	Parameter	Parameter			Units	
V <sub>CC</sub>	Supply Voltage	2.0	3.6	V		
		Data Retention	1.5	3.6	v	
VI	Input Voltage		0	5.5	V	
Vo	Output Voltage	HIGH or LOW State	0	V <sub>CC</sub>	V	
		3-STATE	0	5.5	v	
I <sub>OH</sub> /I <sub>OL</sub>	Output Current	$V_{CC} = 3.0V - 3.6V$		±24		
		$V_{CC} = 3.0V - 3.6V$ $V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±12	mA	
		$V_{CC}=2.3V-2.7V$		±8		
T <sub>A</sub>	Free-Air Operating Temperature		-40	85	°C	
$\Delta t / \Delta V$	Input Edge Rate, V <sub>IN</sub> = 0.8V–2.0V, V <sub>CC</sub> = 3.0V		0	10	ns/V	

±100

-65 to +150

Note 7: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 8:  $\mathrm{I}_{\mathrm{O}}$  Absolute Maximum Rating must be observed.

Note 9: Unused (inputs or I/O's) must be held HIGH or LOW. They may not float.

#### **DC Electrical Characteristics**

Symbol	Parameter	Conditions	V <sub>cc</sub>	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
-		Conditions	(V)	Min	Max	Units
V <sub>IH</sub>	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V <sub>IL</sub>	LOW Level Input Voltage		2.3 – 2.7		0.7	V
		2.7 - 3.6		0.8	v	
V <sub>OH</sub>	HIGH Level Output Voltage	I <sub>OH</sub> = -100 μA	2.3 - 3.6	V <sub>CC</sub> - 0.2		
	I <sub>OH</sub> = -8 mA	2.3	1.8			
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		V
		I <sub>OH</sub> = -18 mA	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V <sub>OL</sub>	LOW Level Output Voltage	I <sub>OL</sub> = 100 μA	2.3 - 3.6		0.2	
		I <sub>OL</sub> = 8 mA	2.3		0.6	
		I <sub>OL</sub> = 12 mA	2.7		0.4	V
		I <sub>OL</sub> = 16 mA	3.0		0.4	
		I <sub>OL</sub> = 24 mA	3.0		0.55	
l <sub>l</sub>	Input Leakage Current	$0 \le V_1 \le 5.5V$	2.3 - 3.6		±5.0	μΑ
l <sub>oz</sub>	3-STATE I/O Leakage	$0 \le V_O \le 5.5V$	2.3 – 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$	2.3 - 3.0		± <b>J</b> .0	μА
I <sub>OFF</sub>	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0	1	10	μA

#### DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V <sub>cc</sub>	T <sub>A</sub> = -40°0	Units	
Symbol	i arameter	Conditions	(V)	Min	Max	Units
I <sub>CC</sub>	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		20	μA
		$3.6V \le V_I, V_O \le 5.5V$ (Note 10)	2.3 - 3.6		±20	μΛ
$\Delta I_{CC}$	Increase in I <sub>CC</sub> per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA

Note 10: Outputs disabled or 3-STATE only.

#### **AC Electrical Characteristics**

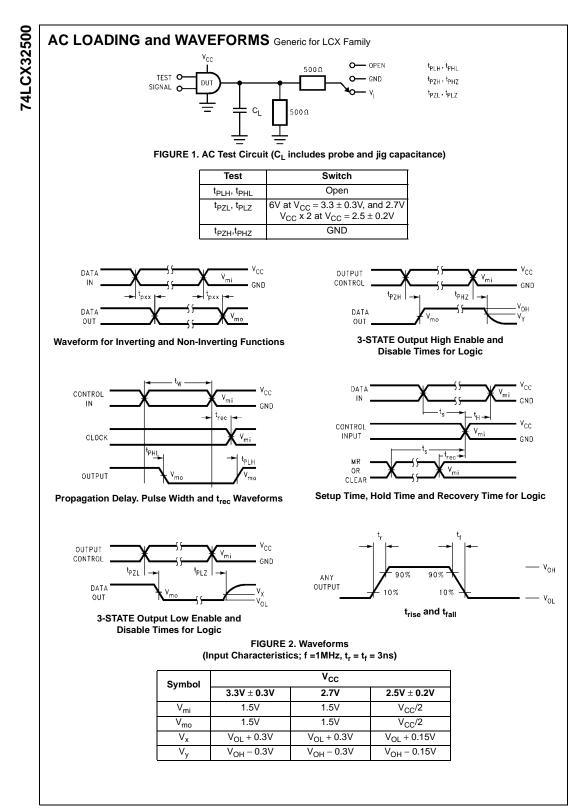
	Parameter		$T_A = -40^{\circ}C$ to $+85^{\circ}C$ , $R_L = 500 \Omega$						
Symbol		V <sub>CC</sub> = 3.	$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V <sub>CC</sub> = 2.7V C <sub>L</sub> = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		
	Farameter	C <sub>L</sub> =							
		Min	Max	Min	Max	Min	Max		
f <sub>MAX</sub>	Maximum Clock Frequency	170						MHz	
t <sub>PHL</sub>	Propagation Delay	1.5	6.0	1.5	7.0	1.5	7.2	ns	
t <sub>PLH</sub>	Bus to Bus	1.5	6.0	1.5	7.0	1.5	7.2	115	
t <sub>PHL</sub>	Propagation Delay	1.5	6.7	1.5	8.0	1.5	8.4		
t <sub>PLH</sub>	Clock to Bus	1.5	6.7	1.5	8.0	1.5	8.4	ns	
t <sub>PHL</sub>	Propagation Delay	1.5	7.0	1.5	8.0	1.5	8.4		
t <sub>PLH</sub>	LE to Bus	1.5	7.0	1.5	8.0	1.5	8.4	ns	
t <sub>PZL</sub>	Output Enable Time	1.5	7.2	1.5	8.2	1.5	9.4	ns	
t <sub>PZH</sub>		1.5	7.2	1.5	8.2	1.5	9.4	115	
t <sub>PLZ</sub>	Output Disable Time	1.5	7.0	1.5	8.0	1.5	8.4		
t <sub>PHZ</sub>		1.5	7.0	1.5	8.0	1.5	8.4	ns	
ts	Setup Time	2.5		2.5		3.0		ns	
t <sub>H</sub>	Hold Time	1.5		1.5		2.0		ns	
t <sub>W</sub>	Pulse Width	3.0		3.0		3.5		ns	

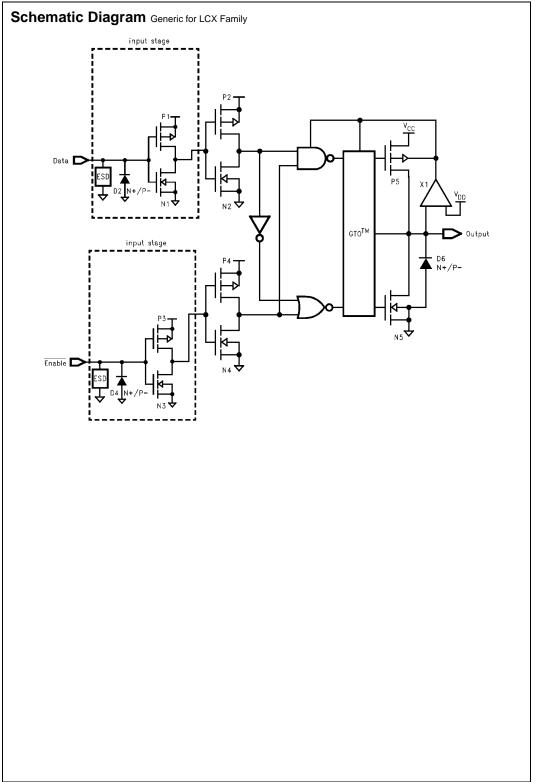
## **Dynamic Switching Characteristics**

Symbol	Parameter	Conditions	V <sub>cc</sub>	$T_A = 25^{\circ}C$	Units
Oymbol		Contactoris	(V)	Typical	Units
V <sub>OLP</sub>	Quiet Output Dynamic Peak V <sub>OL</sub>	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L=30$ pF, $V_{IH}=2.5V,\ V_{IL}=0V$	2.5	0.6	v
V <sub>OLV</sub>	Quiet Output Dynamic Valley VOL	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	-0.6	v

### Capacitance

Symbol	Parameter	Typical	Units	
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C <sub>I/O</sub>	Input/Output Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$	8	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CC} = 3.3V$ , $V_I = 0V$ or $V_{CC}$ , f = 10 MHz	20	pF





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